



MCH6445

N-Channel Power MOSFET 60V, 4A, 78mΩ, Single MCPH6

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Features

- 4V drive
- Low ON-resistance
- Protection diode in

Specifications

Absolute Maximum Ratings at Ta=25°C

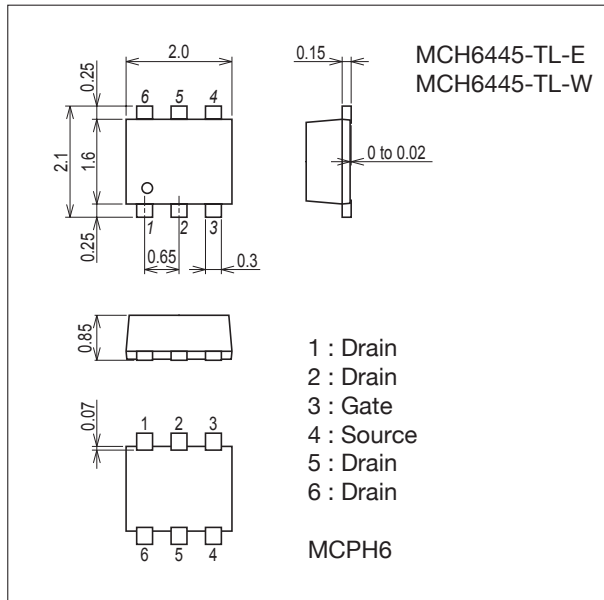
| Parameter | Symbol | Conditions | Ratings | Unit |
|-----------------------------|------------------|--|-------------|------|
| Drain-to-Source Voltage | V _{DSS} | | 60 | V |
| Gate-to-Source Voltage | V _{GSS} | | ±20 | V |
| Drain Current (DC) | I _D | | 4 | A |
| Drain Current (Pulse) | I _{DP} | PW≤10μs, duty cycle≤1% | 16 | A |
| Allowable Power Dissipation | P _D | When mounted on ceramic substrate (1500mm ² ×0.8mm) | 1.5 | W |
| Channel Temperature | T _{ch} | | 150 | °C |
| Storage Temperature | T _{stg} | | -55 to +150 | °C |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Package Dimensions

unit : mm (typ)

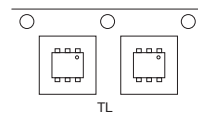
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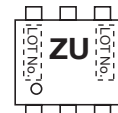
Product & Package Information

- Package : MCPH6
- JEITA, JEDEC : SC-88, SC-70-6, SOT-363
- Minimum Packing Quantity : 3,000 pcs./reel

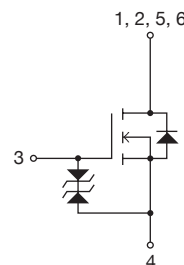
Packing Type : TL



Marking



Electrical Connection



ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

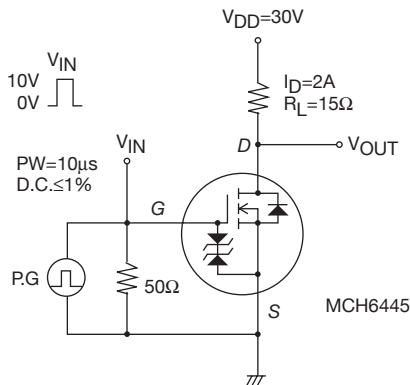
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Electrical Characteristics at Ta=25°C

| Parameter | Symbol | Conditions | Ratings | | | Unit |
|--|---------------|----------------------------------|-----------------------------|------|----------|-----------|
| | | | min | typ | max | |
| Drain-to-Source Breakdown Voltage | $V_{(BR)DSS}$ | $I_D=1mA, V_{GS}=0V$ | 60 | | | V |
| Zero-Gate Voltage Drain Current | I_{DSS} | $V_{DS}=60V, V_{GS}=0V$ | | | 1 | μA |
| Gate-to-Source Leakage Current | I_{GSS} | $V_{GS}=\pm 16V, V_{DS}=0V$ | | | ± 10 | μA |
| Cutoff Voltage | $V_{GS(off)}$ | $V_{DS}=10V, I_D=1mA$ | 1.2 | | 2.6 | V |
| Forward Transfer Admittance | $ y_{fs} $ | $V_{DS}=10V, I_D=2A$ | | 3 | | S |
| Static Drain-to-Source On-State Resistance | $R_{DS(on)1}$ | $I_D=2A, V_{GS}=10V$ | | 60 | 78 | $m\Omega$ |
| | $R_{DS(on)2}$ | $I_D=1A, V_{GS}=4.5V$ | | 74 | 104 | $m\Omega$ |
| | $R_{DS(on)3}$ | $I_D=1A, V_{GS}=4V$ | | 81 | 114 | $m\Omega$ |
| Input Capacitance | C_{iss} | $V_{DS}=20V, f=1MHz$ | | 505 | | pF |
| Output Capacitance | C_{oss} | | | 57 | | pF |
| Reverse Transfer Capacitance | C_{rss} | | | 37 | | pF |
| Turn-ON Delay Time | $t_{d(on)}$ | | See specified Test Circuit. | | 7.3 | |
| Rise Time | t_r | | | 9.8 | | ns |
| Turn-OFF Delay Time | $t_{d(off)}$ | | | 40 | | ns |
| Fall Time | t_f | | | 24 | | ns |
| Total Gate Charge | Q_g | $V_{DS}=30V, V_{GS}=10V, I_D=4A$ | | | 10 | |
| Gate-to-Source Charge | Q_{gs} | | | 1.6 | | nC |
| Gate-to-Drain "Miller" Charge | Q_{gd} | | | 2.1 | | nC |
| Diode Forward Voltage | V_{SD} | $I_S=4A, V_{GS}=0V$ | | 0.82 | 1.2 | V |

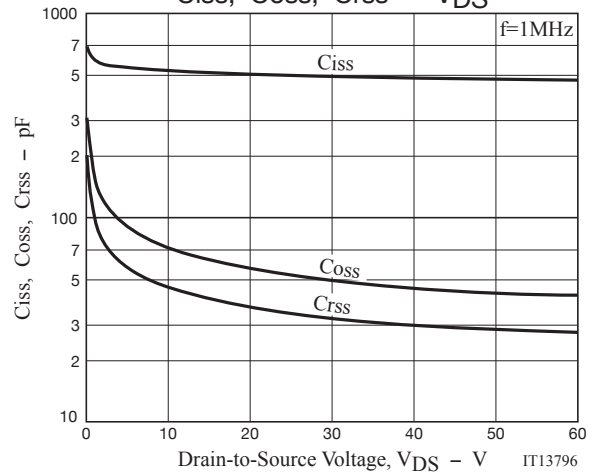
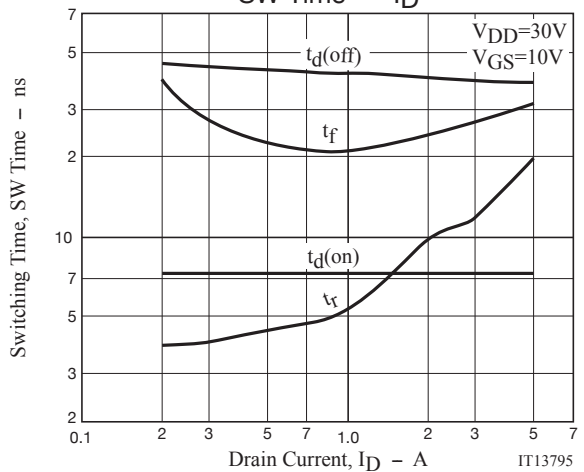
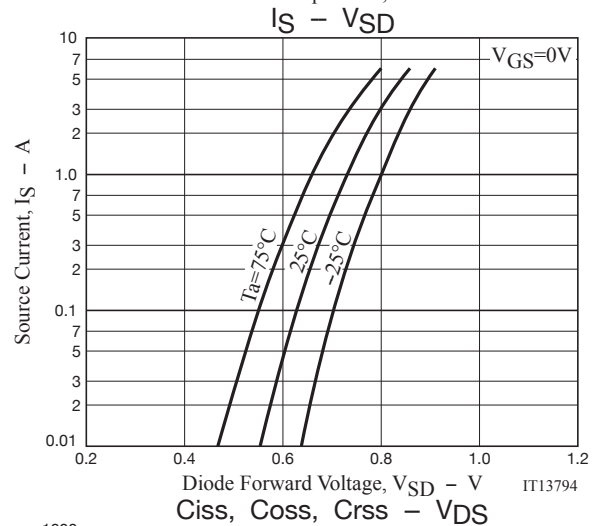
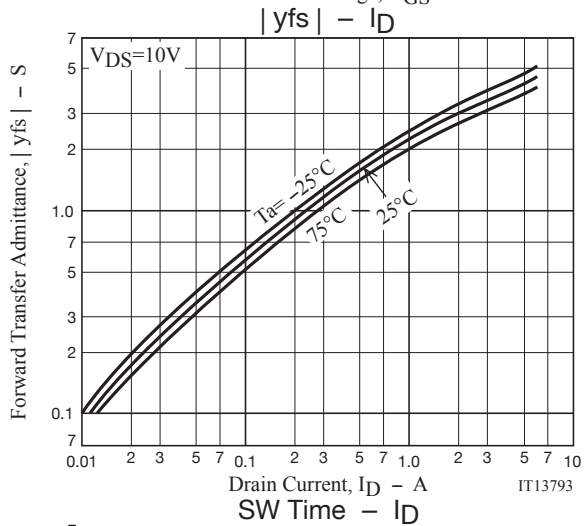
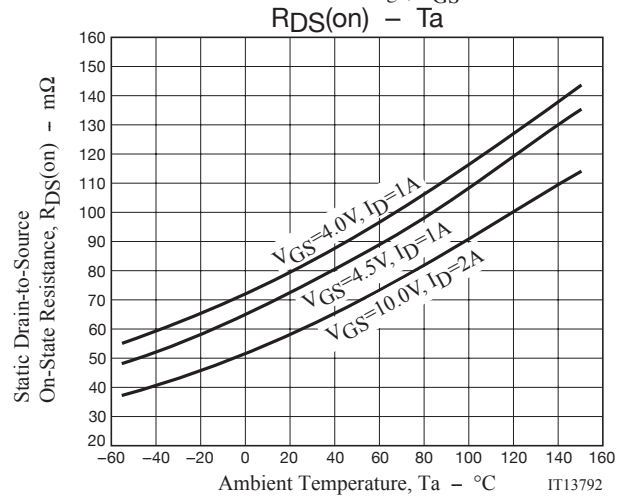
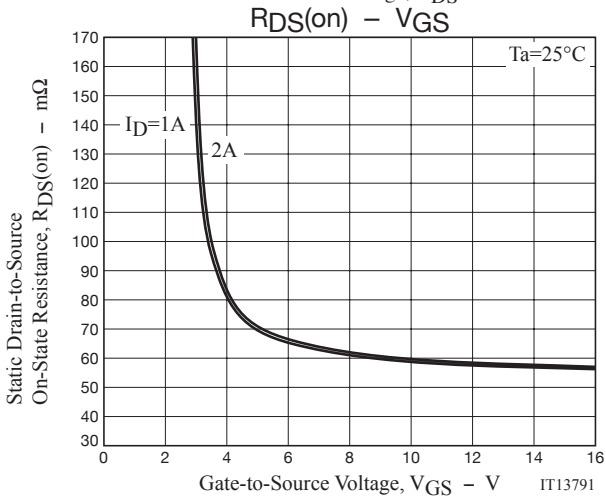
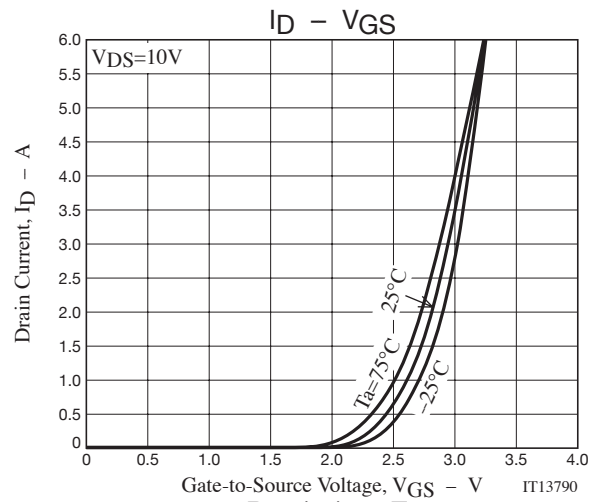
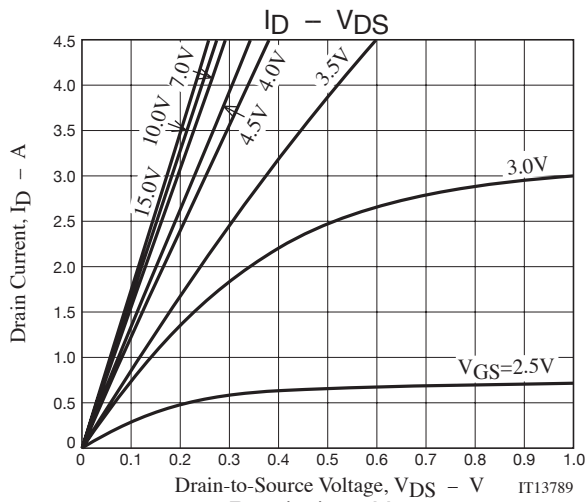
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Switching Time Test Circuit

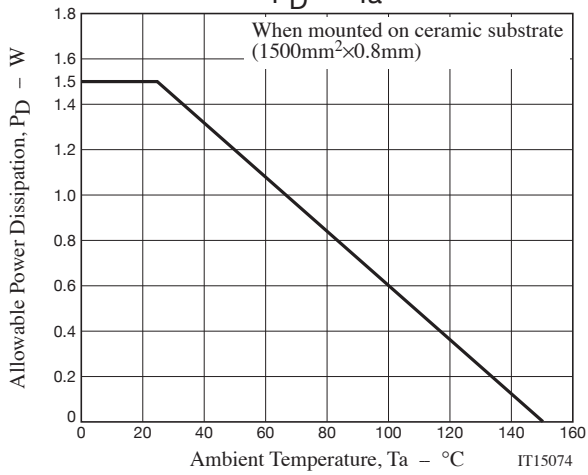
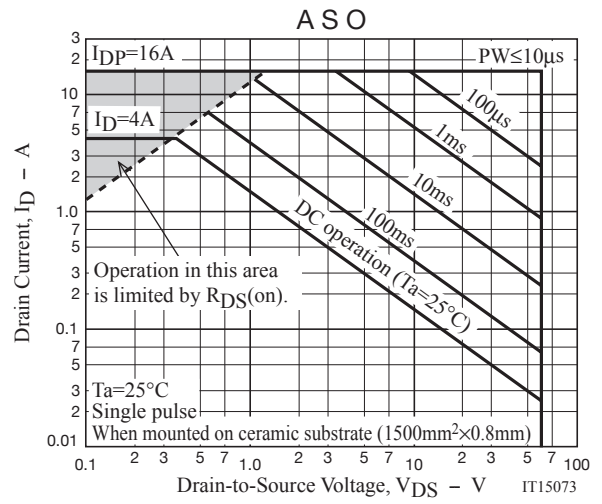
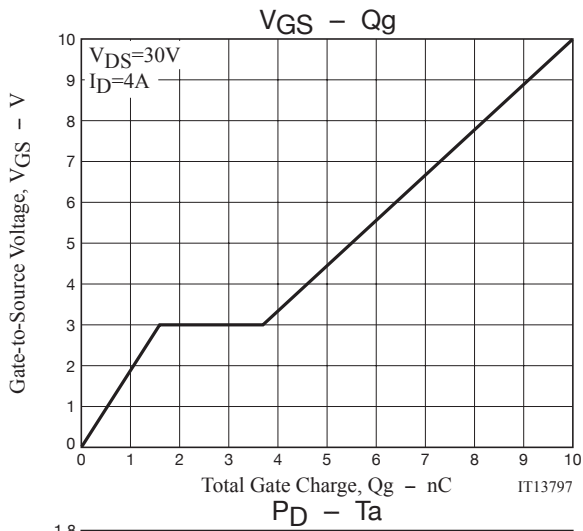


Ordering Information

| Device | Package | Shipping | memo |
|--------------|---------|----------------|--------------------------|
| MCH6445-TL-E | MCPH6 | 3,000pcs./reel | Pb-Free |
| MCH6445-TL-W | | | Pb-Free and Halogen Free |



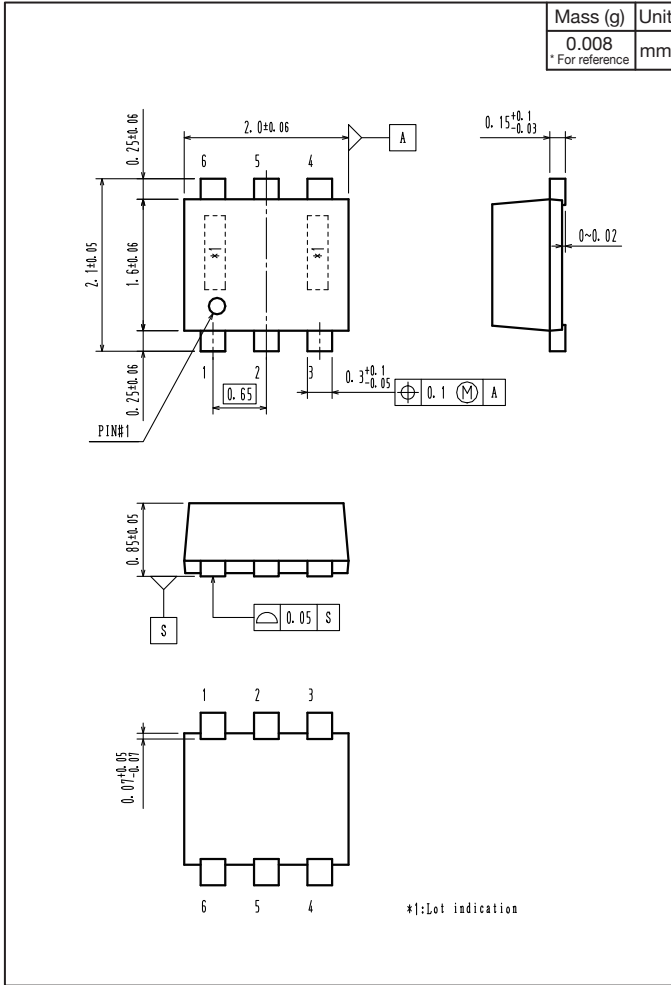
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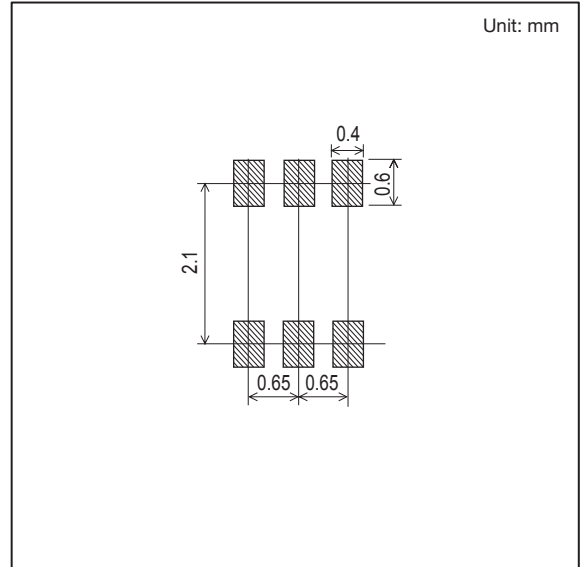
MCH6445

Outline Drawing

MCH6445-TL-E, MCH6445-TL-W



Land Pattern Example



Note on usage : Since the MCH6445 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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